Round Through-Hole LED Lamp (5 mm)



OVLFx3C7 Series

- · High brightness with well-defined spatial radiation patterns
- UV-resistant epoxy lens
- 30° Beam Angle

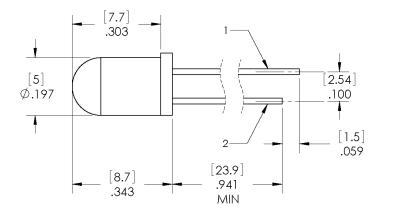


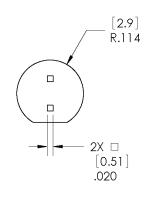
Each device in the **OVLFx3C7** series is a high-intensity LED mounted in a clear plastic T-1¾ package. The LED provides a well-defined and even emission pattern. The UV-resistant epoxy lens makes this device an optimal solution for outdoor applications.

Applications

- Traffic and pedestrian signals
- Signage and architectural lighting
- Backlighting
- Automotive

Part Number	Material	Emitted Color	Intensity Typ. mcd	Lens Color
OVLFB3C7	InGaN	Blue	5,200	Clear
OVLFG3C7	InGaN	Green	16,000	Clear
OVLFR3C7	AllnGaP	Red	7,400	Clear
OVLFY3C7	AllnGaP	Yellow	7,400	Clear





1 ANODE 2 CATHODE

DIMENSIONS ARE IN INCHES AND [MILLIMETERS].



Leadframe material is iron alloy with tin-plated leads

DO NOT LOOK DIRECTLY AT LED WITH UNSHIELDED EYES OR DAMAGE TO RETINA MAY OCCUR.



Absolute Maximum Ratings

 $T_A = 25^{\circ} C$ unless otherwise noted

Storage Temperature Range	-40 ~ +100 ℃			
Operating Temperature Range	-40 ~ +100 ℃			
Reverse Voltage		5 V		
Continuous Forward Current	Blue, Green	25 mA		
Continuous Forward Current	Red, Yellow	50 mA		
Pook Forward Current (400/ Duty Cycle 4 kHz)	Blue, Green	100 mA		
Peak Forward Current (10% Duty Cycle, 1 kHz)	Red, Yellow	100 mA		
Device Discinction	Blue, Green	100 mW		
Power Dissipation	Red, Yellow	120 mW		
Command Linearity on Amphiant Taranavatura	Blue, Green	-0.29 mA/°C		
Current Linearity vs Ambient Temperature	Red, Yellow	-0.72 mA/°C		
Electrostatic Discharge Classification (JEDEC-JESD22-A114F)	Class 1C			
LED Junction Temperature		125°C		
Lead Soldering Temperature (4 mm from the base of the epoxy bulk	Lead Soldering Temperature (4 mm from the base of the epoxy bulb)			

Electrical Characteristics

 $T_A = 25^{\circ} C$ unless otherwise noted

SYMBOL	PARAMETER	COLOR	MIN	TYP	MAX	UNITS	CONDITIONS	
		Blue	3,115	5,200				
,	Luminous Intensity	Green	8,550	16,000		mad	J 00 A	
I _V	Luminous Intensity	Red	4,360	7,400		mcd	$I_F = 20 \text{ mA}$	
		Yellow	4,360	7,400				
		Blue	2.6	3.4	4.0			
V_{F}	Forward Voltage	Green	2.0	3.4	4.0	V	I _F = 20 mA	
۷F	Forward voltage	Red	1.8	2.0	2.4	V	IF = 20 IIIA	
		Yellow	1.0	2.0	2.4			
	Reverse Current	Blue			10	μA		
,		Green	d				$V_R = 5 V$	
I _R		Red					V _R = 5 V	
		Yellow						
		Blue	460	470	475			
λ	Dominant Wavelength	Green	519	525	531	nm	L = 20 mΛ	
λ_{D}	Dominant wavelength	Red	620	623	630	11111	$I_F = 20 \text{ mA}$	
		Yellow	585	589	595			
		Blue						
۸.)	Spectra Half Width	Green	 - -	25			I _F = 20 mA	
Δλ	Spectra Half Width	Red		20		nm	I _F = 20 IIIA	
		Yellow						
2Θ½H-H	50% Power Angle			30		deg	I _F = 20 mA	



Standard Bins

LEDs are sorted to luminous intensity (I_V), forward voltage (V_F) and dominant wavelength (nm) bins listed below. Each bag consists of a single intensity bin, single voltage bin and a single color bin. Orders are filled using all intensity and color bins listed in the following tables. Optek will not accept orders for single intensity bins, single voltage bins or single color bins.

Luminous Intensity (I_V) @ 20mA

BLUE: OVLFB3C7						
IV Code	IV Code Min (mcd) Max (mcd)					
0V	3,115	4,360				
OW	4,360	6,105				
0X	6,105	8,550				
0Y	8,550	11,970				
GRE	EEN: OVLFG	3C7				
IV Code	Min (mcd)	Max (mcd)				
0Y	8,550	11,670				
0Z	11,970	16,758				
Z1	16,758	23,500				
Z2	23,500	32,800				

Forward Voltage (V_F)

BLUE: OVLFB3C7 & GREEN: OVLFG3C7					
VF Code	Min	Max			
Α	2.6	2.8			
В	2.8	3.0			
O	3.0	3.2			
D	3.2	3.4			
E	3.4	3.6			
F	3.6	3.8			
G	3.8	4.0			
•					

Dominant Wavelength (nm)

BLUE: OVLFB3C7						
Color Code	Color Code Min (nm) Max (nm)					
ВС	460	465				
BD	465	470				
BE	BE 470 475					
GREEN: OVLFG3C7						
Color Code Min (nm) Max (nm)						
FB	519	523				
FC	523	527				
FD	527	531				
-						

Luminous Intensity (I_V) @ 20mA RED: OVLFR3C7

IV Code	Min (mcd)	Max (mcd)
OW	4,360	6,105
0X	6,105	8,550
0Y	8,550	11,970
0Z	11,970	16,758
YELI	_OW: OVLFY	3C7
IV Code	Min (mcd)	Max (mcd)
OW	4,360	6,105
0X	6,105	8,550
0Y	8,550	11,970
0Y 0Z	8,550 11,970	11,970 16,758

Forward Voltage (V_F)

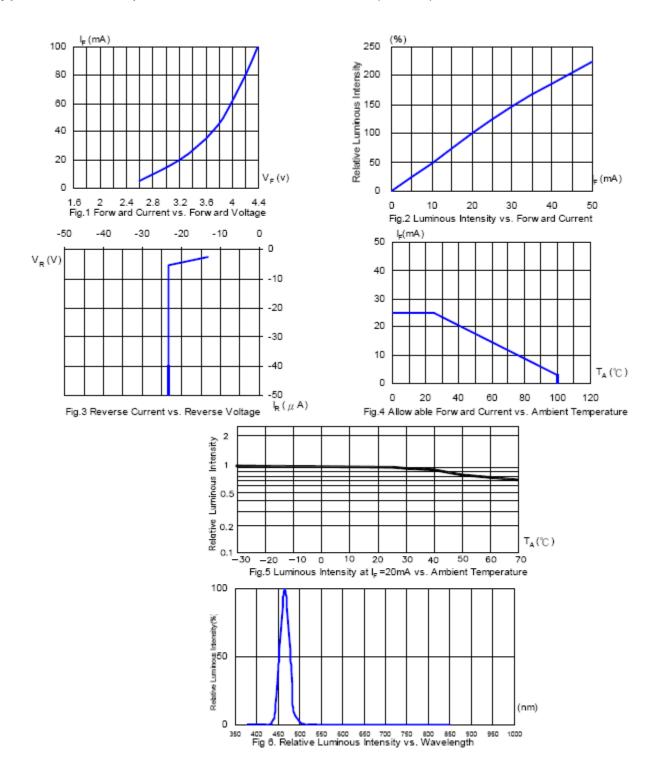
RED: OVLFR3C7 & YELLOW: OVLFY3C7						
VF Code	Min	Max				
Α	1.8	2.0				
В	2.0	2.2				
С	2.2	2.4				

Dominant Wavelength (nm) RED: OVLFR3C7

Color Code	Min (nm)	Max (nm)
RA	620	625
RB	625	630
	•	
YELI	LOW: OVLFY	3C7
Color Code	Min (nm)	Max (nm)
YC	585	587
YD	587	589
YE	589	591
YF	591	593
YG	593	595

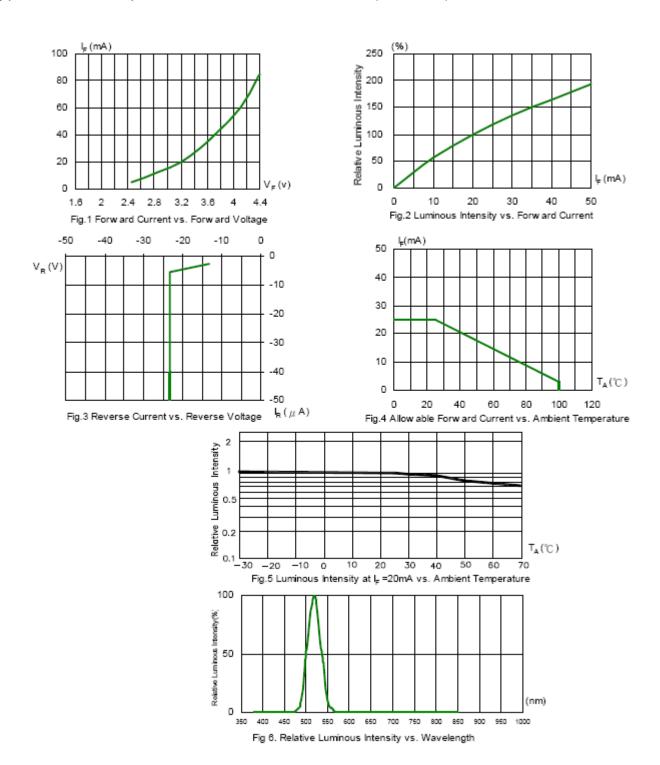


Typical Electro-Optical Characteristics Curves (BLUE)



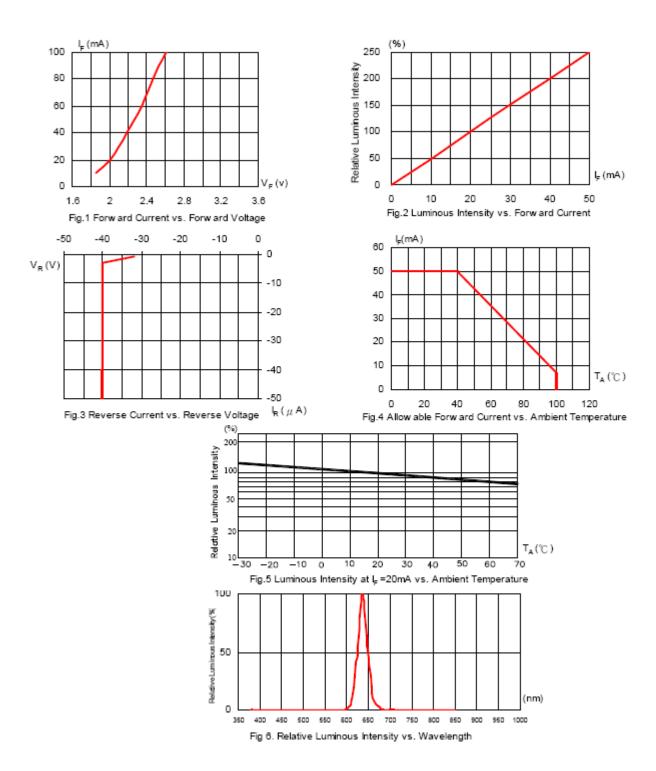


Typical Electro-Optical Characteristics Curves (GREEN)



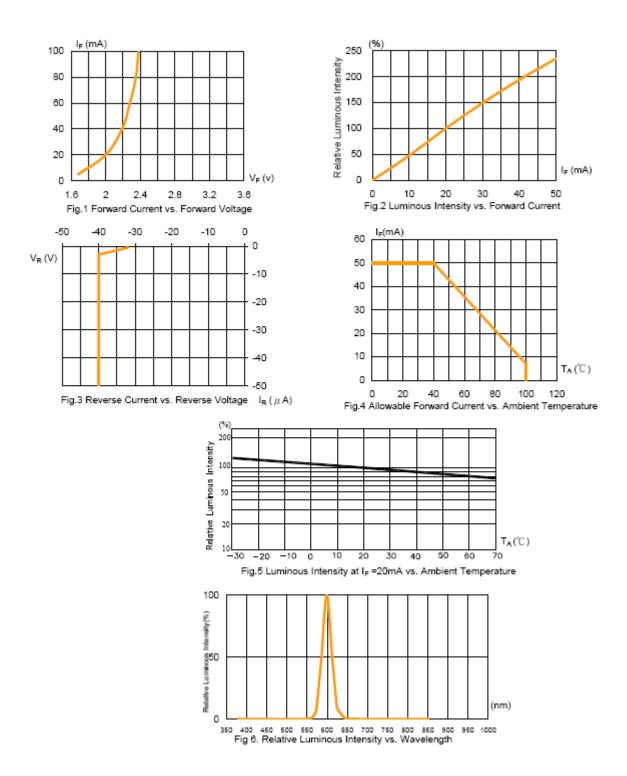


Typical Electro-Optical Characteristics Curves (RED)





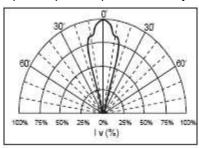
Typical Electro-Optical Characteristics Curves (YELLOW)



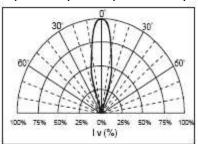


Beam Pattern

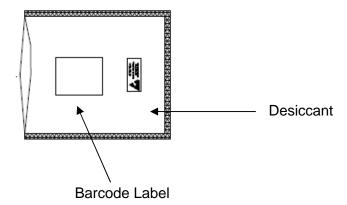
(RED) and (YELLOW)



(BLUE) and (GREEN)



Packaging: 500 pcs per bulk bag with desiccant





Reliability Test

LED lamps are checked by reliability tests based on MIL standards.

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Classi- fication	Test Item	Standard Test Method	Test Conditions	Duration	Unit	Acc / Rej Criteria	Result
Life	Operation Life Test	MIL-STD-750D	$T_A=25^{\circ}C$, $I_F=30mA$ *	1000 Hrs	100	0 / 1	Pass
Test	(OLT)	Method 1026.3	1 _A -25 C * IF -50IIA	1000 1115	100	071	rass
	High Temperature	MIL-STD-750D	T _A =100°C	1000 Hrs	100	0 / 1	Dass
	Storage (HTS)	Method 1032.1	1 _A -100 C	1000 Hrs	100	0 / 1	Pass
	Low Temperature	MIL-STD-750D	T _A =-40°C	1000 Hes	100	0 / 1	Pass
Test	Storage (LTS)	Method 1032.1	1 _A 40 C	1000 Hrs	100	0/1	
Environment Test	Temp. & Humidity	MIL-STD-750D	T _Δ =85°C , Rh=85% I _F =20mA **	500 Hrs	100	0 / 1	Pass
ronn	with Bias (THB)	Method 103B	1 _A -65 C / Kli-65/6 1 _F -20llA	300 HIS	100	071	Pass
Envi	Thermal Shock	MIL-STD-750D	0°C ~ 100°C	100	100	0 / 1	Pass
	Test (TST)	Method 1056.1	2min 2min	cycles	100	0/1	Pass
	Temperature	MIL-STD-750D	-40°C ~ 25°C~ 100°C ~ 25°C	100	100	0 / 1	Dave
	Cycling Test (TCT)	Method 1051.5	30min 5min 30min 5min	cycles	100	0 / 1	Pass
		MIL-STD-750D	235±5°C → 5 sec		20	0.71	
lest	Solderability	Method 2026.4		1 time	20	0 / 1	Pass
Mechanical Test	Resistance to	MIL-STD-750D	26015°C - 10	1 time	20	0 / 1	Pass
thami	Soldering Heat	Method 2031.1	260±5°C → 10 sec				
Мес	T 17	MIL-STD-750D	Load 2.5N (0.25kgf)		20	0.11	
	Lead Integrity	Method 2036.3	$0^{\circ} \sim 90^{\circ} \sim 0^{\circ}$, bend	3 times	20	0 / 1	Pass

Remark : (*) I_{F} =30mA for AlInGaP chip ; I_{F} =20mA for InGaN chip

(**) I_{F} =20mA for AlInGaP chip $\, ; \, I_{F}$ =10mA for InGaN chip

2. Failure Criteria (T_A =25°C):

Test Item S	Symbol	Test Conditions	Criteria for Judgment			
	Symbol		Min.	Max.		
Luminous Intensity	$I_{ m V}$	I _F =20 mA	LSL×0.7 **			
Voltage (Forward)	V_{F}	I _F =20 mA		USL×1.1 *		

(*) USL : Upper Standard Level , (**) LSL : Lower Standard Level

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